

Standard Rectifier Module

$$V_{RRM} = 2 \times 1400 \text{ V}$$

$$I_{FAV} = 310 \text{ A}$$

$$V_F = 1.03 \text{ V}$$

Phase leg

Part number

MDD312-14N1



Backside: isolated

 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: Y1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling

Disclaimer Notice

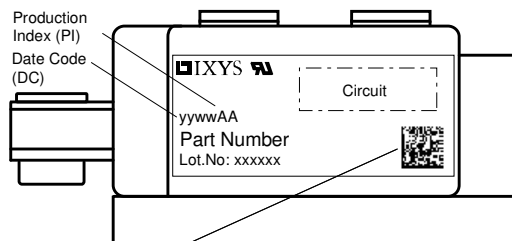
Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.



Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					1500	V
V_{RRM}	max. repetitive reverse blocking voltage					1400	V
I_R	reverse current	$V_R = 1400$ V		$T_{VJ} = 25^\circ\text{C}$		500	μA
		$V_R = 1400$ V		$T_{VJ} = 150^\circ\text{C}$		30	mA
V_F	forward voltage drop	$I_F = 300$ A		$T_{VJ} = 25^\circ\text{C}$		1.13	V
		$I_F = 600$ A				1.33	V
		$I_F = 300$ A		$T_{VJ} = 125^\circ\text{C}$		1.03	V
		$I_F = 600$ A				1.29	V
I_{FAV}	average forward current	$T_C = 100^\circ\text{C}$		$T_{VJ} = 150^\circ\text{C}$		310	A
$I_{F(RMS)}$	RMS forward current	180° sine	d = 0.5			520	A
V_{F0}	threshold voltage	} for power loss calculation only		$T_{VJ} = 150^\circ\text{C}$		0.80	V
r_F	slope resistance					0.6	m Ω
R_{thJC}	thermal resistance junction to case					0.12	K/W
R_{thCH}	thermal resistance case to heatsink				0.04		K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		1040	W
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		10.8	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		11.7	kA
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		9.18	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		9.92	kA
I^2t	value for fusing	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		583.2	kA ² s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		566.1	kA ² s
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 150^\circ\text{C}$		421.4	kA ² s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		409.0	kA ² s
C_J	junction capacitance	$V_R = 400$ V; f = 1 MHz		$T_{VJ} = 25^\circ\text{C}$		381	pF



Package Y1			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			600	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				680		g
M_D	mounting torque		4.5		7	Nm
M_T	terminal torque		11		13	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	16.0			mm
$d_{Spb/Apb}$		terminal to backside	16.0			mm
V_{ISOL}	isolation voltage	t = 1 second	3600			V
		t = 1 minute	3000			V



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD312-14N1	MDD312-14N1	Box	3	463434

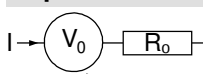
Similar Part	Package	Voltage class
MDD312-12N1	Y1-CU	1200
MDD312-16N1	Y1-CU	1600
MDD312-18N1	Y1-CU	1800
MDD312-20N1	Y1-CU	2000

MDD312-22N1	Y1-CU	2200
-------------	-------	------

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}\text{C}$

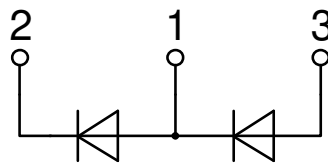
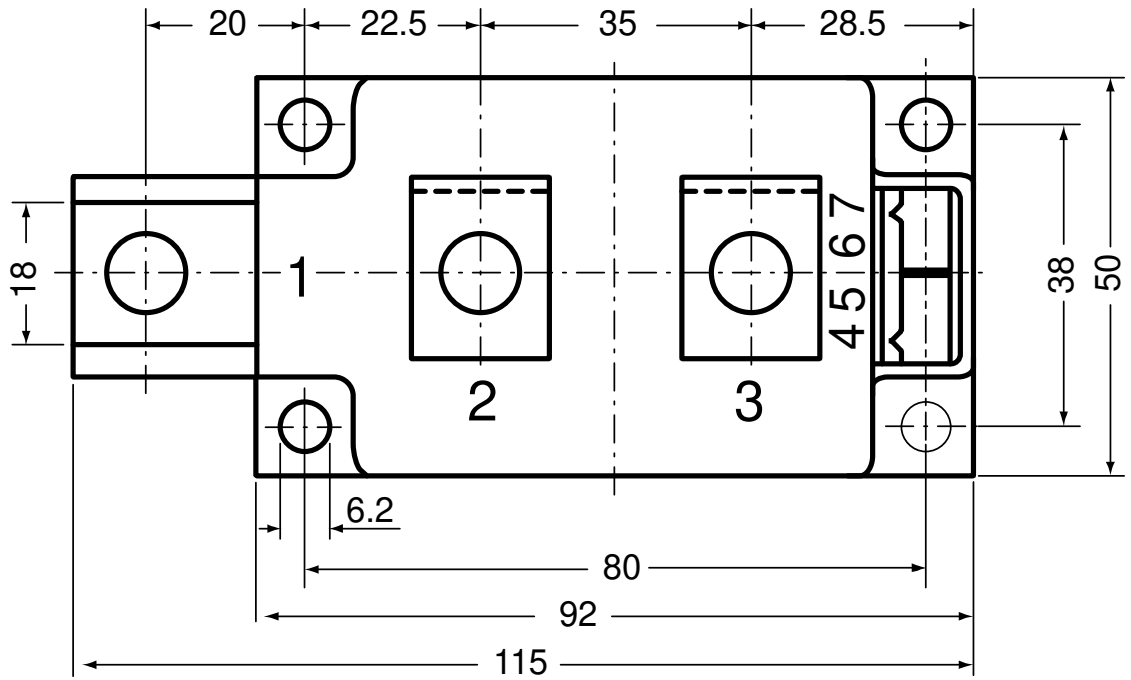
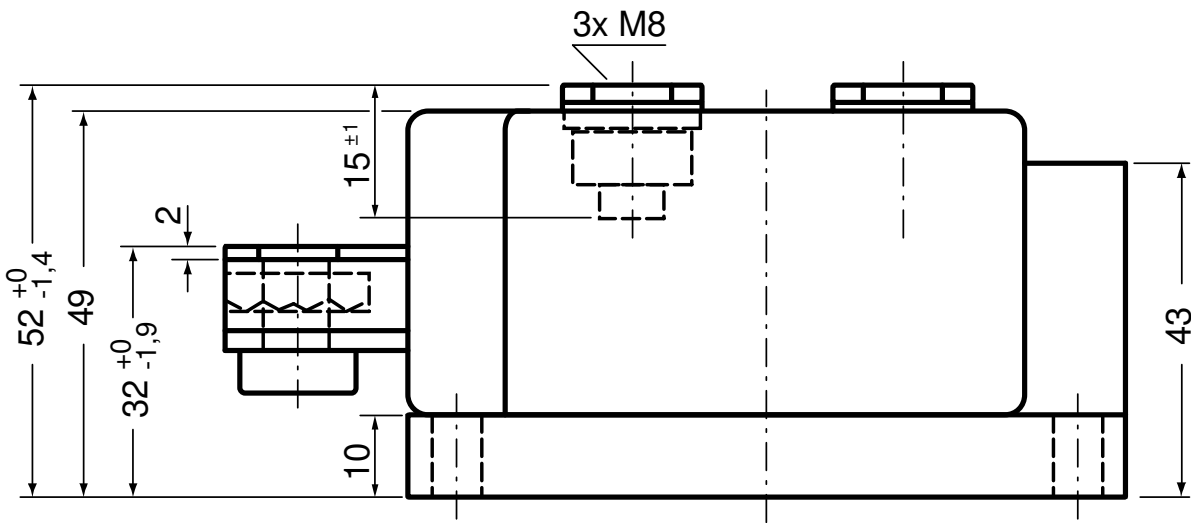


Rectifier

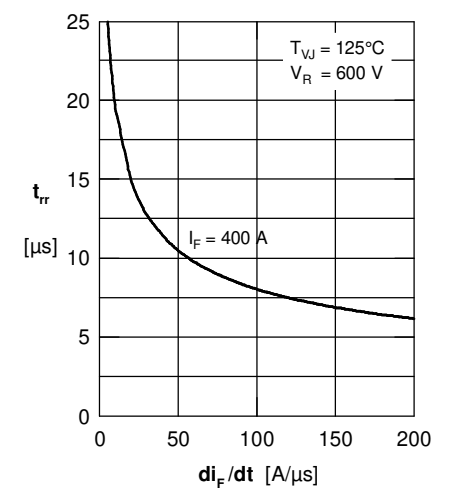
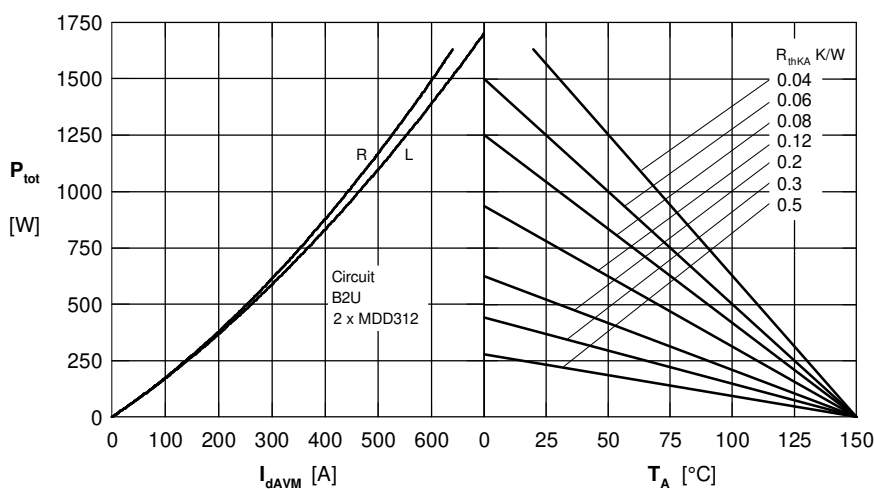
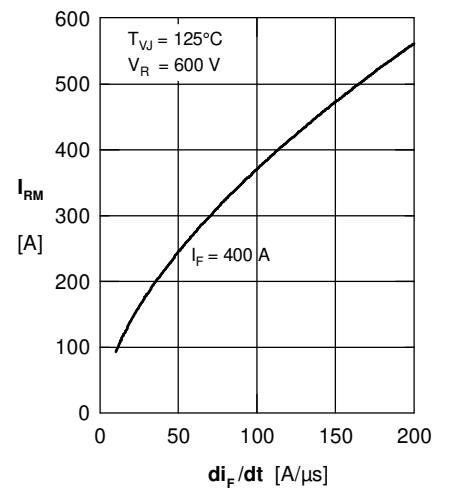
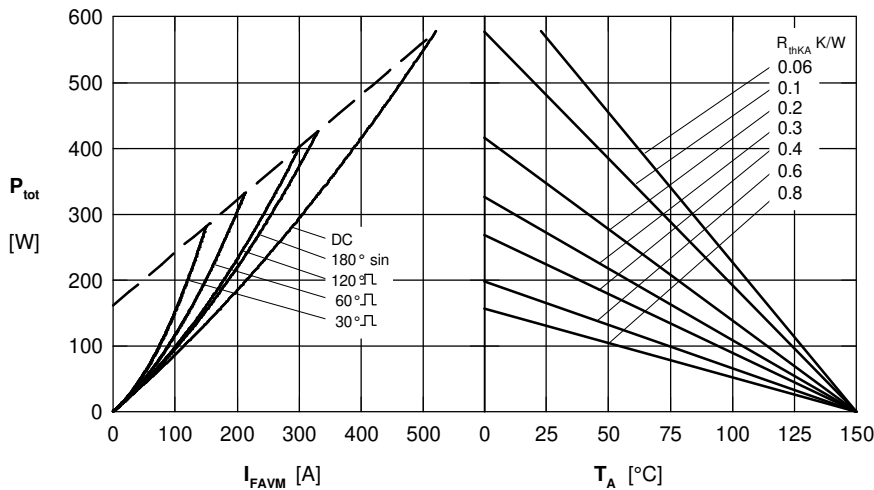
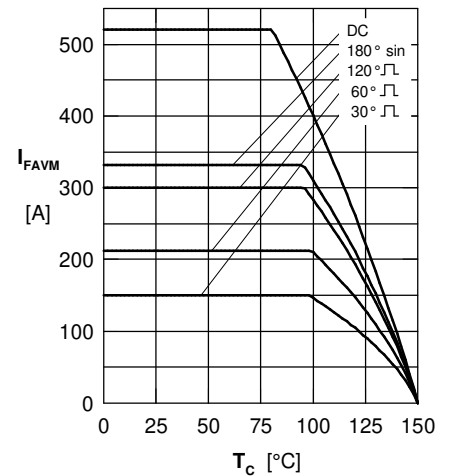
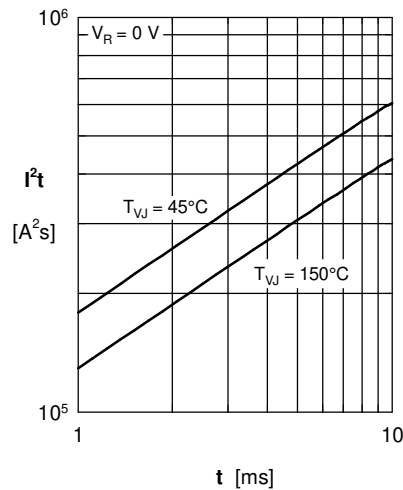
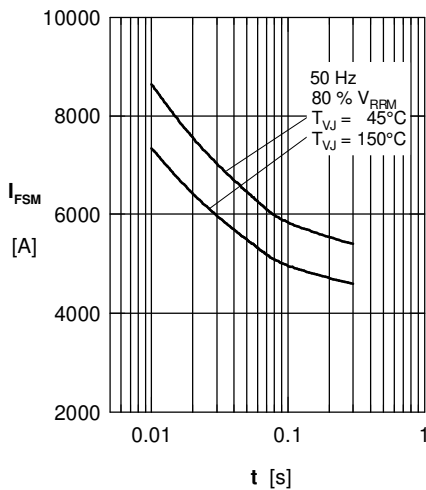
$V_{0\ max}$	threshold voltage	0.8	V
$R_{0\ max}$	slope resistance *	0.4	mΩ



Outlines Y1



Rectifier





Rectifier

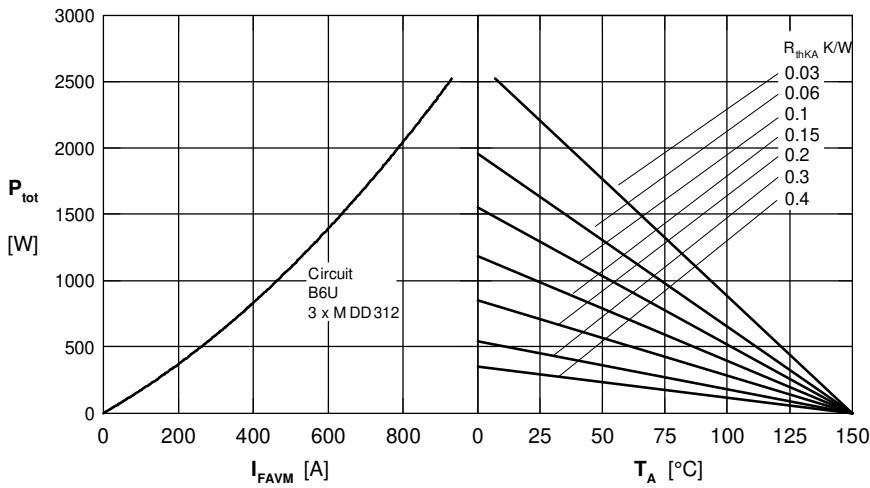
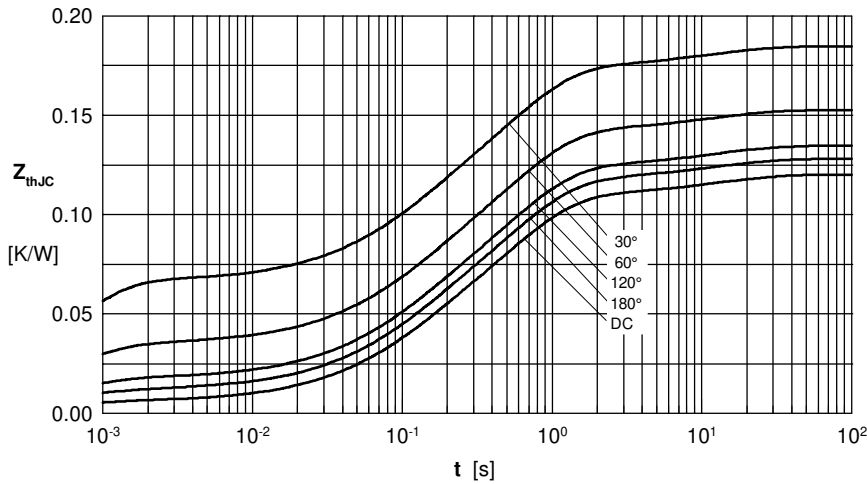


Fig. 8 Three phase rectifier bridge: Power dissipation vs. direct output current & ambient temperature



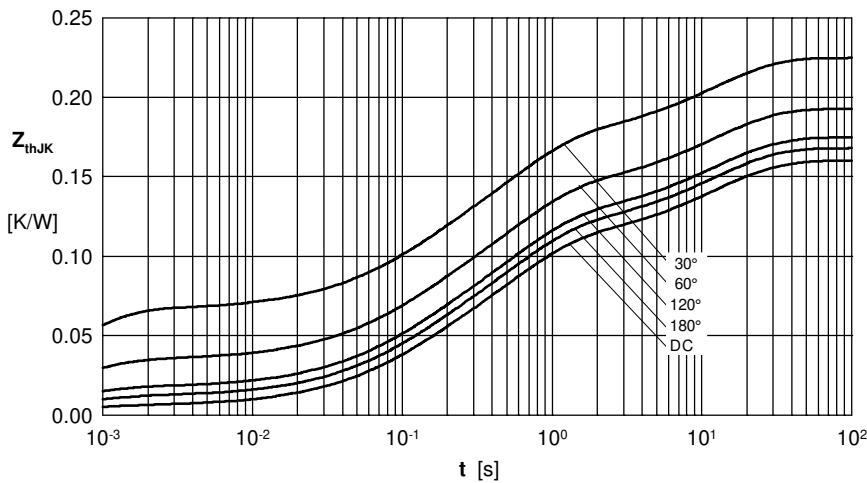
R_{thJC} for various conduction angles d :

d	R_{thJC} [K/W]
DC	0.120
180°	0.128
120°	0.135
60°	0.153
30°	0.185

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0058	0.00054
2	0.0310	0.09800
3	0.0720	0.54000
4	0.0112	12.0000

Fig. 9 Transient thermal impedance junction to case (per diode)



R_{thJK} for various conduction angles d :

d	R_{thJK} [K/W]
DC	0.160
180°	0.168
120°	0.175
60°	0.193
30°	0.225

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0058	0.00054
2	0.0310	0.09800
3	0.0720	0.54000
4	0.0112	12.0000
5	0.0400	12.0000

Fig. 10 Transient thermal impedance junction to heatsink (per diode)